
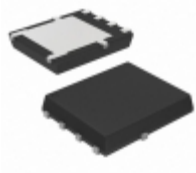
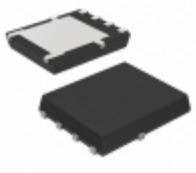
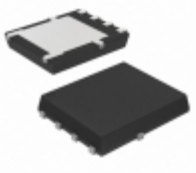
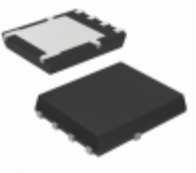
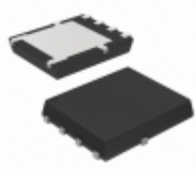
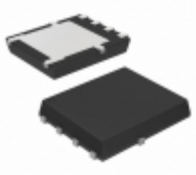
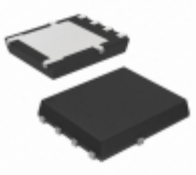
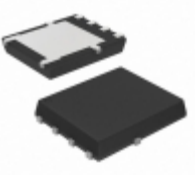
	<h2 style="color: red;">NTMFS5844NLT1G</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">NTMFS5844NLT1G</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 60A SO-8FL</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">NTMFS5844NLT1G.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 4280 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">NTMFS5844NLT1G</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 60V 60A SO-8FL
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	4280 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Verlustleistung (max)	3.7W (Ta), 107W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	11.2A (Ta)
Rds On (Max) @ Id, Vgs	12 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	2.3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1460pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Original-Reel®

NTMFS5844NLT1G ist neu im Original, Suche NTMFS5844NLT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMFS5844NLT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMFS5844NLT1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTMFS5832NLT1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 110A SO-8FL</p>	 <p><b>NTMFS5C404NLT3G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 47A SO8FL</p>	 <p><b>NTMFS5C404NLTWFT1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 352A SO8FL</p>	 <p><b>NTMFS5C404NLTT1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 352A SO8FL</p>
 <p><b>NTMFS5834NLT1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 13A SO-8FL</p>	 <p><b>NTMFS5C404NLTT3G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 352A SO8FL</p>	 <p><b>NTMFS5830NLT1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 28A SO-8FL</p>	 <p><b>NTMFS4H02NT1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 37A SO8FL</p>

### heiße Teile

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Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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